NSN 5962-01-146-9000

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-146-9000 **Body Length:**1.290 inches

Between 0.500 inches and 0.610 inches

Body Height: 0.220 inches

Body Width:

Maximum Power Dissipation Rating:

1.0 watts

Operating Tempurature Range:

-55.0/+100.0 degrees celsius

Storage Tempurature Range:

-55.0/+125.0 degrees celsius

Features Provided:

Electrostatic sensitive and ultraviolet erasable and monolithic and programmable

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

N-type metal oxide-semiconductor logic

Input Circuit Pattern:

13 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

26.0 volts power source

Memory Device Type:

Rom

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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